

R1Q2A3636B/R1Q2A3618B/R1Q2A3609B

36-Mbit QDR™II SRAM 2-word Burst

> REJ03C0341-0003 Preliminary Rev. 0.03 Apr. 11, 2008

Description

The R1Q2A3636B is a 1,048,576-word by 36-bit, the R1Q2A3618B is a 2,097,152-word by 18-bit, and the R1Q2A3609B is a 4,194,304-word by 9-bit synchronous quad data rate static RAM fabricated with advanced CMOS technology using full CMOS six-transistor memory cell. It integrates unique synchronous peripheral circuitry and a burst counter. All input registers controlled by an input clock pair (K and /K) and are latched on the positive edge of K and /K. These products are suitable for applications which require synchronous operation, high speed, low voltage, high density and wide bit configuration. These products are packaged in 165-pin plastic FBGA package.

Features

- 1.8 V \pm 0.1 V power supply for core (V_{DD})
- 1.4 V to V_{DD} power supply for I/O (V_{DDO})
- DLL circuitry for wide output data valid window and future frequency scaling
- Separate independent read and write data ports with concurrent transactions
- 100% bus utilization DDR read and write operation
- Two-tick burst for low DDR transaction size
- Two input clocks (K and /K) for precise DDR timing at clock rising edges only
- Two output clocks (C and /C) for precise flight time and clock skew matching-clock and data delivered together to receiving device
- Internally self-timed write control
- Clock-stop capability with µs restart
- User programmable impedance output
- Fast clock cycle time: 4.0 ns (250 MHz)/5.0 ns (200 MHz)/6.0 ns (167 MHz)
- Simple control logic for easy depth expansion
- JTAG boundary scan

Notes: QDR RAMs and Quad Data Rate RAMs comprise a new family of products developed by Cypress Semiconductor, IDT, NEC, Samsung, and Renesas Technology Corp.

Preliminary: The specifications of this device are subject to change without notice. Please contact your nearest

Renesas Technology's Sales Dept. regarding specifications.



Ordering Information

	Part N	umber	Organization	Cycle	Clock	Package	Notes
				time	frequency		
R1Q2A3636B			1-M word	4.0 ns	250 MHz	Plastic FBGA 165-pin	
R1Q2A3636B			× 36-bit	5.0 ns	200 MHz	PLBG0165FB-A	
	R1Q2A3636BBG-60R			6.0 ns	167 MHz		
	R1Q2A3618BBG-40R		2-M word	4.0 ns	250 MHz		
R1Q2A3618B	BG-50	R	× 18-bit	5.0 ns	200 MHz		
R1Q2A3618B	BG-60	R		6.0 ns	167 MHz		
R1Q2A3609B	BG-40	R	4-M word	4.0 ns	250 MHz		
R1Q2A3609B	BG-50	R	× 9-bit	5.0 ns	200 MHz		
R1Q2A3609B	BG-60	R		6.0 ns	167 MHz		
Notes:							
1. Part No	umber						
(0:1)	R1	: Renesas Memory ¡	: Renesas Memory prefix			: 1 st Generation	
(2:3)	Q2	: QDRII 2-word Burs	st SRAM		Α	: 2 nd Generation	
	Q3	: QDRII 4-word Burs	t SRAM		В	: 3 rd Generation	
	Q4	: DDRII 2-word Burs	t SRAM	(10:11)	BG	: Package type=BGA	
	Q5	: DDRII 4-word Burs	t SRAM	(12:13)	60	: Cycle time=6.0 ns	
	Q6	: DDRII 2-word Burs	t SRAM		50	: Cycle time=5.0 ns	
		Separate I/O			40	: Cycle time=4.0 ns	
(4)	Α	: V _{DD} =1.8V			33	: Cycle time=3.3 ns	
(5:6)	36	: Density = 36Mb		(14)	R	: Temperature range= 0°C	~70°C
	72	: Density = 72Mb			I	: Temperature range= -40	°C ~85°C
(7:8)	36	: Organization = x36		(15)	В	: Pb-free	
	18	: Organization = x18			T	: Tape&Reel	
	09	: Organization = x9			S	: Pb-free and Tape&Reel	
					None	: Standard (Pb and Tray)	
				(16)	0 ~9 , A ~Z	:Renesas internal use	
2. Marking Na	me						
		Name(0:14) =Part Nu					
M	larking	Name(0:16) =Part Nu	mber(0:14)+Bx	Pt	o-free (x=0 ~	9 , A ~Z)	
(E	Exampl	e) R1Q2A3609BBG-6		. ~			
		R1Q2A3609BBG-6	0RB0	Pb-free			

Pin Arrangement

R1Q2A3636B series

	1	2	3	4	5	6	7	8	9	10	11
Α	/CQ	Vss	NC	/W	/BW2	/K	/BW1	/R	SA	NC	CQ
В	Q27	Q18	D18	SA	/BW3	K	/BW0	SA	D17	Q17	Q8
С	D27	Q28	D19	Vss	SA	SA	SA	Vss	D16	Q7	D8
D	D28	D20	Q19	Vss	Vss	Vss	Vss	Vss	Q16	D15	D7
Е	Q29	D29	Q20	VDDQ	Vss	Vss	Vss	VDDQ	Q15	D6	Q6
F	Q30	Q21	D21	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	D14	Q14	Q5
G	D30	D22	Q22	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	Q13	D13	D5
Н	/DOFF	VREF	VDDQ	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	VDDQ	VREF	ZQ
J	D31	Q31	D23	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	D12	Q4	D4
K	Q32	D32	Q23	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	Q12	D3	Q3
L	Q33	Q24	D24	VDDQ	Vss	Vss	Vss	VDDQ	D11	Q11	Q2
М	D33	Q34	D25	Vss	Vss	Vss	Vss	Vss	D10	Q1	D2
N	D34	D26	Q25	Vss	SA	SA	SA	Vss	Q10	D9	D1
Р	Q35	D35	Q26	SA	SA	С	SA	SA	Q9	D0	Q0
R	TDO	TCK	SA	SA	SA	/C	SA	SA	SA	TMS	TDI

(Top View)

R1Q2A3618B series

	1	2	3	4	5	6	7	8	9	10	11
Α	/CQ	Vss	SA	/W	/BW1	/K	NC	/R	SA	NC	CQ
В	NC	Q9	D9	SA	NC	K	/BW0	SA	NC	NC	Q8
С	NC	NC	D10	Vss	SA	SA	SA	Vss	NC	Q7	D8
D	NC	D11	Q10	Vss	Vss	Vss	Vss	Vss	NC	NC	D7
Е	NC	NC	Q11	VDDQ	Vss	Vss	Vss	VDDQ	NC	D6	Q6
F	NC	Q12	D12	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	NC	Q5
G	NC	D13	Q13	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	NC	D5
Н	/DOFF	VREF	V _{DDQ}	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	VDDQ	VREF	ZQ
J	NC	NC	D14	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	Q4	D4
K	NC	NC	Q14	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	D3	Q3
L	NC	Q15	D15	VDDQ	Vss	Vss	Vss	VDDQ	NC	NC	Q2
М	NC	NC	D16	Vss	Vss	Vss	Vss	Vss	NC	Q1	D2
N	NC	D17	Q16	Vss	SA	SA	SA	Vss	NC	NC	D1
Р	NC	NC	Q17	SA	SA	С	SA	SA	NC	D0	Q0
R	TDO	TCK	SA	SA	SA	/C	SA	SA	SA	TMS	TDI

(Top View)

R1Q2A3636B/R1Q2A3618B/R1Q2A3609B

R1Q2A3609B series

	1	2	3	4	5	6	7	8	9	10	11
Α	/CQ	Vss	SA	/W	NC	/K	NC	/R	SA	SA	CQ
В	NC	NC	NC	SA	NC	K	/BW	SA	NC	NC	Q4
С	NC	NC	NC	Vss	SA	SA	SA	Vss	NC	NC	D4
D	NC	D5	NC	Vss	Vss	Vss	Vss	Vss	NC	NC	NC
Е	NC	NC	Q5	VDDQ	Vss	Vss	Vss	VDDQ	NC	D3	Q3
F	NC	NC	NC	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	NC	NC
G	NC	D6	Q6	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	NC	NC
Н	/DOFF	VREF	V _{DDQ}	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	VDDQ	VREF	ZQ
J	NC	NC	NC	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	Q2	D2
K	NC	NC	NC	VDDQ	V _{DD}	Vss	V _{DD}	VDDQ	NC	NC	NC
L	NC	Q7	D7	VDDQ	Vss	Vss	Vss	VDDQ	NC	NC	Q1
М	NC	NC	NC	Vss	Vss	Vss	Vss	Vss	NC	NC	D1
N	NC	D8	NC	Vss	SA	SA	SA	Vss	NC	NC	NC
Р	NC	NC	Q8	SA	SA	С	SA	SA	NC	D0	Q0
R	TDO	TCK	SA	SA	SA	/C	SA	SA	SA	TMS	TDI

(Top View)

Notes: 1. Address expansion order for future higher density SRAMs (i.e. $72Mb \rightarrow 144Mb \rightarrow 288Mb$): $(9A \rightarrow 3A \rightarrow 10A) \rightarrow 2A \rightarrow 7A \rightarrow 5B$.

Pin Description

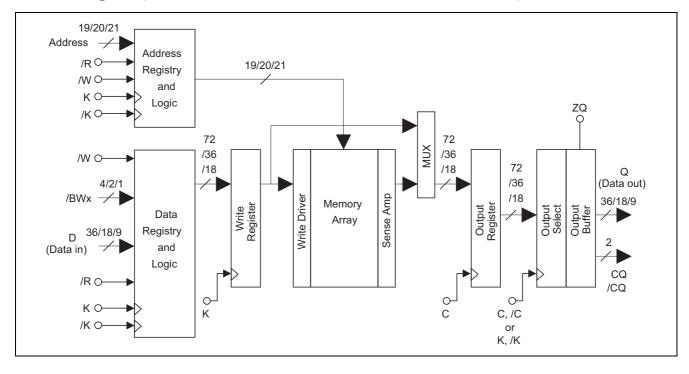
Name	I/O type	Descriptions	Notes
SA	Input	Synchronous address inputs: These inputs are registered and must meet the setup and hold times around the rising edge of K for READ cycles and must meet the setup and hold times around the rising edge of /K for WRITE cycles. All transactions operate on a burst-of-two words (one clock period of bus activity). These inputs are ignored when device is deselected.	
/R	Input	Synchronous read: When low, this input causes the address inputs to be registered and a READ cycle to be initiated. This input must meet setup and hold times around the rising edge of K.	
/W	Input	Synchronous write: When low, this input causes the address inputs to be registered and a WRITE cycle to be initiated. This input must meet setup and hold times around the rising edge of K.	
/BWx	Input	Synchronous byte writes: When low, these inputs cause their respective byte to be registered and written during WRITE cycles. These signals must meet setup and hold times around the rising edges of K and /K for each of the two rising edges comprising the WRITE cycle. See Byte Write Truth Table for signal to data relationship.	
K, /K	Input	Input clock: This input clock pair registers address and control inputs on the rising edge of K, and registers data on the rising edge of K and the rising edge of /K. /K is ideally 180 degrees out of phase with K. All synchronous inputs must meet setup and hold times around the clock rising edges. These balls cannot remain V_{REF} level.	
C, /C	Input	Output clock: This clock pair provides a user-controlled means of tuning device output data. The rising edge of /C is used as the output timing reference for first output data. The rising edge of C is used as the output timing reference for second output data. Ideally, /C is 180 degrees out of phase with C. C and /C may be tied high to force the use of K and /K as the output reference clocks instead of having to provide C and /C clocks. If tied high, C and /C must remain high and not to be toggled during device operation. These balls cannot remain V_{REF} level.	
/DOFF	Input	DLL disable: When low, this input causes the DLL to be bypassed for /DOFF Input stable, low frequency operation.	
ZQ	Input	Output impedance matching input: This input is used to tune the device outputs to the system data bus impedance. Q and CQ output impedance are set to $0.2 \times RQ$, where RQ is a resistor from this ball to ground. This ball can be connected directly to V_{DDQ} , which enables the minimum impedance mode. This ball cannot be connected directly to V_{SS} or left unconnected.	
TMS TDI	Input	IEEE1149.1 test inputs: 1.8 V I/O levels. These balls may be left not TMS Input connected if the JTAG function is not used in the circuit.	
TCK	Input	IEEE1149.1 clock input: 1.8 V I/O levels. This ball must be tied to V _{SS} if the JTAG function is not used TCK Input in the circuit.	
D ₀ to D _n	Input	Synchronous data inputs: Input data must meet setup and hold times around the rising edges of K and /K during WRITE operations. See Pin Arrangement figures for ball site location of individual signals. The ×9 device uses D0 to D8. Remaining signals are not used. The ×18 device uses D0 to D17. Remaining signals are not used. The ×36 device uses D0 to D35.	
CQ, /CQ	Output	Synchronous echo clock outputs: The edges of these outputs are tightly matched to the synchronous data outputs and can be used as a data valid indication. These signals run freely and do not stop when Q tristates.	
TDO	Output	IEEE 1149.1 test output: 1.8 V I/O level.	
Q ₀ to Q _n	Output	Synchronous data outputs: Output data is synchronized to the respective C and /C, or to the respective K and /K if C and /C are tied high. This bus operates in response to /R commands. See Pin Arrangement figures for ball site location of individual signals. The ×9 device uses Q0 to Q8. Remaining signals are not used. The ×18 device uses Q0 to Q17. Remaining signals are not used. The ×36 device uses Q0 to Q35.	



Name	I/O type	Descriptions	Notes
V_{DD}	Supply	Power supply: 1.8 V nominal. See DC Characteristics and Operating V _{DD} Supply Conditions for range.	
V_{DDQ}	Supply	Power supply: Isolated output buffer supply. Nominally 1.5 V. 1.8 V is also permissible. See DC Characteristics and Operating Conditions for range.	
V_{SS}	Supply	Power supply: Ground.	
V_{REF}	_	HSTL input reference voltage: Nominally V _{DDQ} /2, but may be adjusted to improve system noise margin. Provides a reference voltage for the HSTL input buffers.	
NC	_	No connect: These signals are not internally connected. These signals can be left floating or connected to ground to improve package heat dissipation.	

Notes: 1. All power supply and ground balls must be connected for proper operation of the device.

Block Diagram (R1Q2A3636B / R1Q2A3618B / R1Q2A3609B series)



RENESAS

General Description

Power-up and Initialization Sequence

The following supply voltage application sequence is recommended: V_{SS} , V_{DD} , V_{DDQ} , V_{REF} then V_{IN} .

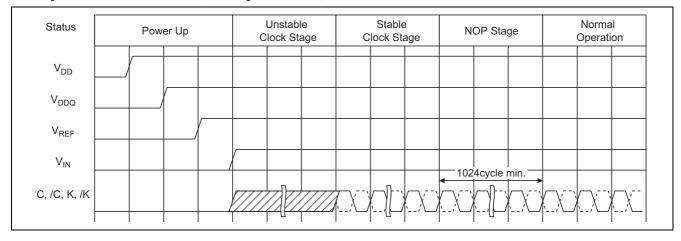
After the stable power, there are three possible sequences.

- Sequence when DLL disable (/DOFF pin fixed low)
 Just after the stable power and clock (K, /K, C, /C), 1024 NOP cycles (min.) are required for all operations, including JTAG functions, to become normal.
- 2a. Sequence controlled by /DOFF pin when DLL enable

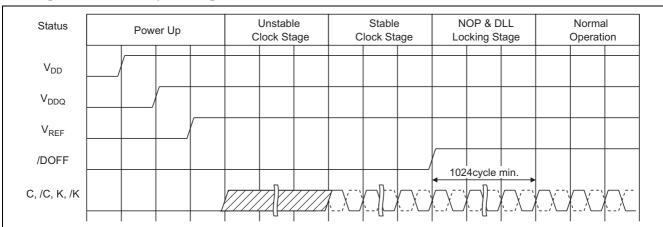
 Just after the stable power and clock (K, /K, C, /C), take /DOFF to be high.

 The additional 1024 NOP cycles (min.) are required to lock the DLL and for all operations to become normal.
- 2b. Sequence controlled by Clock (/DOFF pin fixed high) when DLL enable If /DOFF pin is fixed high with unstable clock, the clock (K, /K, C, /C) must be stopped for 30ns (min.). During stop clock stage, C pin must tie low for 30 ns (min.). C, /C, K and /K cannot remain V_{REF} level. The additional 1024 NOP cycles (min.) are required to lock the DLL and for all operations to become normal.
- Notes: 1. After K or C clock is stopped, clock recovery cycles (1024 NOP cycles (min.)) are required for read/write operations to become normal.
 - 2. When DLL is enable and the operating frequency is changed, DLL reset should be required again. After DLL reset again, the 1024 NOP cycles (min.) are needed to lock the DLL.

1. Sequence when DLL disable (/DOFF pin fixed low)

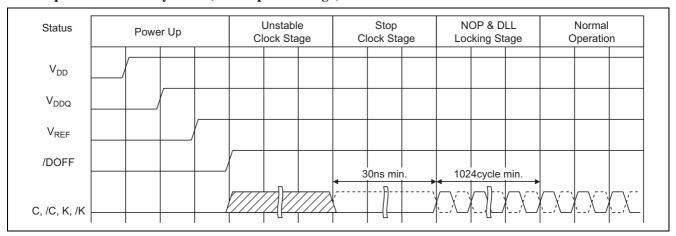


2a. Sequence controlled by /DOFF pin when DLL enable





2b. Sequence controlled by Clock (/DOFF pin fixed high) when DLL enable



DLL Constraints

- 1. DLL uses either K or C clock as its synchronizing input, the input should have low phase jitter which is specified as TKC var.
- 2. The lower end of the frequency at which the DLL can operate is 119MHz.

Programmable Output Impedance

1. Output buffer impedance can be programmed by terminating the ZQ ball to Vss through a precision resistor (RQ). The value of RQ is five times the output impedance desired. The allowable range of RQ to guarantee impedance matching with a tolerance of 10% is 250Ω typical.

The total external capacitance of ZQ ball must be less than 7.5 pF.

K Truth Table

Operation	K	/R	/W	D or Q			
Write Cycle:	1	×	L	Data in			
Load address, input write data on				Input data	D(A+0)	D(A+1)	
consecutive K and /K rising edges				Output clock	K(t)↑	/K(t)↑	
Read Cycle:	↑	L	×	Data out	Data out		
Load address, output read data on				Output data	Q(A+0)	Q(A+1)	
consecutive C and /C rising edges				Output clock	/C(t+1)↑	C(t+2)↑	
NOP (No operation)	↑	Н	Н	$D = \times$ or $Q = High-Z$			
Standby (Clock stopped)	Stopped	×	×	Previous state			

Notes: 1. H: high level, L: low level, ×: don't care, ↑: rising edge.

- 2. Data inputs are registered at K and /K rising edges. Data outputs are delivered at C and /C rising edges, except if C and /C are high, then data outputs are delivered at K and /K rising edges.
- 3. /R and /W must meet setup/hold times around the rising edges (low to high) of K and are registered at the rising edge of K.
- 4. This device contains circuitry that will ensure the outputs will be in high-Z during power-up.
- 5. Refer to state diagram and timing diagrams for clarification.
- 6. When clocks are stopped, the following cases are recommended; the case of K = low, /K = high, C = low and /C = high, or the case of K = high, /K = low, C = high and /C = low. This condition is not essential, but permits most rapid restart by overcoming transmission line charging symmetrically.

Byte Write Truth Table (x36)

Operation	K	/K	/BW0	/BW1	/BW2	/BW3
Write D0 to D35	1	_	L	L	L	L
	_	1	L	L	L	L
Write D0 to D8	1	_	L	Н	Н	Н
	_	1	L	Н	Н	Н
Write D9 to D17	1	_	Н	L	Н	Н
	_	1	Н	L	Н	Н
Write D18 to D26	1	_	Н	Н	L	Н
	_	1	Н	Н	L	Н
Write D27 to D35	1	_	Н	Н	Н	L
	_	1	Н	Н	Н	L
Write nothing	1	_	Н	Н	Н	Н
	_	1	Н	Н	Н	Н

Notes: 1. H: high level, L: low level, ↑: rising edge.

2. Assumes a WRITE cycle was initiated. /BWx can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

Byte Write Truth Table (x18)

Operation	K	/K	/BW0	/BW1
Write D0 to D17	1	_	L	L
		↑	L	L
Write D0 to D8	1	_	L	Н
	_	1	L	Н
Write D9 to D17	1	_	Н	L
	_	1	Н	L
Write nothing	1	_	Н	Н
	_	1	Н	Н

Notes: 1. H: high level, L: low level, ↑: rising edge.

2. Assumes a WRITE cycle was initiated. /BWx can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

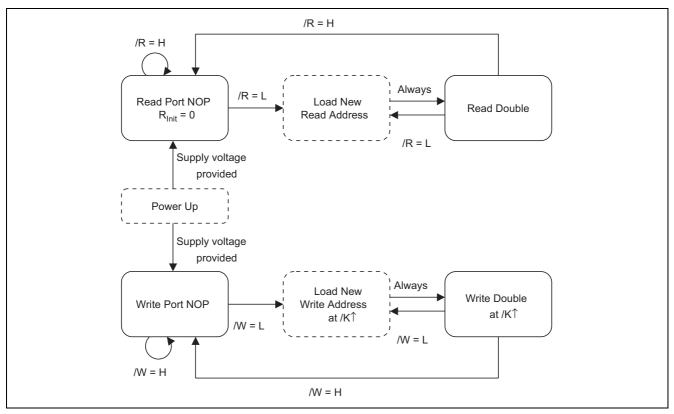
Byte Write Truth Table (x9)

Operation	K	/K	/BW
Write D0 to D8	1	_	L
	_	1	L
Write nothing	1	_	Н
	_	1	Н

Notes: 1. H: high level, L: low level, ↑: rising edge.

2. Assumes a WRITE cycle was initiated. /BWx can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

Bus Cycle State Diagram



Notes: 1. The address is concatenated with one additional internal LSB to facilitate burst operation. The address order is always fixed as: xxx...xxx+0, xxx...xxx+1.

Bus cycle is terminated at the end of this sequence (burst count = 2).

- 2. Read and write state machines can be active simultaneously.
- 3. State machine control timing sequence is controlled by ${\sf K}.$

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit	Notes
Input voltage on any ball	V _{IN}	-0.5 to V _{DD} + 0.5 (2.5 V max.)	V	1, 4
Input/output voltage	V _{I/O}	-0.5 to V _{DDQ} + 0.5 (2.5 V max.)	V	1, 4
Core supply voltage	V_{DD}	−0.5 to 2.5	V	1, 4
Output supply voltage	V_{DDQ}	−0.5 to V _{DD}	V	1, 4
Junction temperature	Tj	+125 (max)	°C	
Storage temperature	T _{STG}	−55 to +125	°C	

Notes: 1. All voltage is referenced to $V_{\rm SS}$.

- 2. Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted the Operation Conditions. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.
- 3. These CMOS memory circuits have been designed to meet the DC and AC specifications shown in the tables after thermal equilibrium has been established.
- 4. The following supply voltage application sequence is recommended: V_{SS}, V_{DD}, V_{DDQ}, V_{REF} then V_{IN}. Remember, according to the Absolute Maximum Ratings table, V_{DDQ} is not to exceed 2.5 V, whatever the instantaneous value of V_{DDQ}.

Recommended DC Operating Conditions

 $(Ta = 0 \text{ to } +70^{\circ}\text{C})$

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Power supply voltagecore	V_{DD}	1.7	1.8	1.9	V	
Power supply voltageI/O	V_{DDQ}	1.4	1.5	V_{DD}	V	
Input reference voltageI/O	V_{REF}	0.68	0.75	0.95	V	1
Input high voltage	V _{IH (DC)}	V _{REF} + 0.1	_	$V_{DDQ} + 0.3$	V	2, 3
Input low voltage	V _{IL (DC)}	-0.3	_	V _{REF} – 0.1	V	2, 3

Notes: 1. Peak to peak AC component superimposed on V_{REF} may not exceed 5% of V_{REF}.

2. Overshoot: $V_{IH (AC)} \le V_{DDQ} + 0.5 V$ for $t \le t_{KHKH}/2$

Undershoot: $V_{IL\ (AC)} \ge -0.5\ V$ for $t \le t_{KHKH}/2$

Power-up: $V_{IH} \le V_{DDQ}$ + 0.3 V and $V_{DD} \le 1.7$ V and $V_{DDQ} \le 1.4$ V for $t \le 200$ ms

During normal operation, V_{DDQ} must not exceed V_{DD} .

Control input signals may not have pulse widths less than t_{KHKL} (min) or operate at cycle rates less than t_{KHKH} (min).

During normal operation, $V_{IH(DC)}$ must not exceed V_{DDQ} and $V_{IL(DC)}$ must not be lower than V_{SS} .

3. These are DC test criteria. The AC V_{IH} / V_{IL} levels are defined separately to measure timing parameters.

DC Characteristics

 $(Ta = 0 \text{ to } +70^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V})$

			-40	-50	-60		
Paramete	er	Symbol	Max	Max	Max	Unit	Notes
Operating supply current	(×9)	I _{DD}	600	550	500	mA	1, 2, 3
(READ / WRITE)	(×18)	I _{DD}	650	600	550	mA	1, 2, 3
	(×36)	I _{DD}	700	650	600	mA	1, 2, 3
Standby supply current (NOP)	(×9 / ×18 / ×36)	I _{SB1}	350	340	330	mA	2, 4, 5



R1Q2A3636B/R1Q2A3618B/R1Q2A3609B

Parameter	Symbol	Min	Max	Unit	Test conditions	Notes
Input leakage current	I _{LI}	-2	2	μA		10
Output leakage current	I _{LO}	-5	5	μA		11
Output high voltage	V _{OH} (Low)	V _{DDQ} -0.2	V_{DDQ}	V	$ I_{OH} \le 0.1 \text{ mA}$	8, 9
	V _{OH}	V _{DDQ} /2 -0.08	V _{DDQ} /2 +0.08	V	Note 6	8, 9
Output low voltage	V _{OL} (Low)	V _{SS}	0.2	V	$I_{OL} \le 0.1 \text{ mA}$	8, 9
	V _{OL}	V _{DDQ} /2 -0.08	V _{DDQ} /2 +0.08	V	Note 7	8, 9

Notes: 1. All inputs (except ZQ, V_{REF}) are held at either V_{IH} or V_{IL} .

- 2. $I_{OUT} = 0$ mA. $V_{DD} = V_{DD}$ max, $t_{KHKH} = t_{KHKH}$ min.
- 3. Operating supply currents are measured at 100% bus utilization.
- 4. All address / data inputs are static at either $V_{IN} > V_{IH}$ or $V_{IN} < V_{IL}$.
- 5. Reference value (Condition=NOP currents are valid when entering NOP after all pending READ and WRITE cycles are completed.)
- 6. Outputs are impedance-controlled. $|I_{OH}| = (V_{DDQ}/2)/(RQ/5)$ for values of 175 $\Omega \le RQ \le 350 \Omega$.
- 7. Outputs are impedance-controlled. I_{OL} = $(V_{DDQ}/2)/(RQ/5)$ for values of 175 $\Omega \le RQ \le 350 \ \Omega$.
- 8. AC load current is higher than the shown DC values. AC I/O curves are available upon request.
- 9. HSTL outputs meet JEDEC HSTL Class I standards.
- $10.0 \le V_{IN} \le V_{DDQ}$ for all input balls (except V_{REF} , ZQ, TCK, TMS, TDI ball).
- 11. $0 \le V_{OUT} \le V_{DDQ}$ (except TDO ball), output disabled.

Thermal Resistance

Parameter	Symbol	Тур	Unit	Notes
Junction to Ambient	$ heta_{JA}$	24.5	°C/W	
Junction to Case	$\theta_{\sf JC}$	5.6	°C/W	

Note: These parameters are calculated under the condition of wind velocity = 1 m/s.

Capacitance

$$(Ta = +25^{\circ}C, f=1.0MHz, V_{DD} = 1.8V, V_{DDO} = 1.5V)$$

Parameter	Symbol	Min	Тур	Max	Unit	Test conditions	Notes
Input capacitance	C _{IN}	_	2	3	pF	V _{IN} = 0 V	1, 2
Clock input capacitance	C _{CLK}	_	2	3	pF	V _{CLK} = 0 V	1, 2
Input/output capacitance (D, Q, ZQ)	C _{I/O}	_	3	4.5	pF	V _{I/O} = 0 V	1, 2

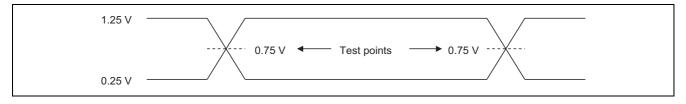
Notes: 1. These parameters are sampled and not 100% tested.

2. Except JTAG (TCK, TMS, TDI, TDO) pins.

AC Test Conditions

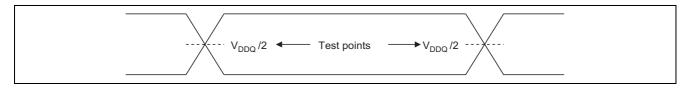
$$(Ta = 0 \text{ to } +70^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V})$$

Input waveform (Rise/fall time ≤ 0.3 ns)

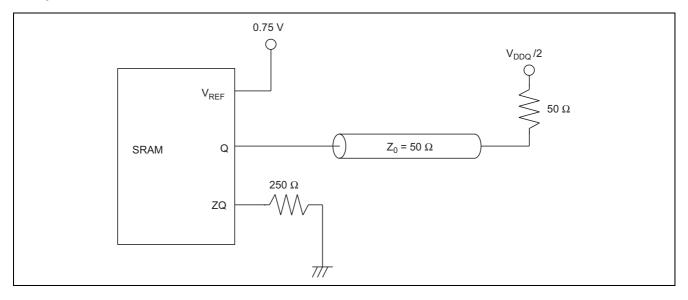




Output waveform



Output load condition



AC Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Input high voltage	V _{IH (AC)}	V _{REF} + 0.2		_	V	1, 2, 3, 4
Input low voltage	V _{IL (AC)}		_	$V_{\text{REF}}-0.2$	V	1, 2, 3, 4

Notes: 1. All voltages referenced to V_{SS} (GND).

- 2. These conditions are for AC functions only, not for AC parameter test.
- 3. Overshoot: $V_{IH (AC)} \le V_{DDQ} + 0.5 V$ for $t \le t_{KHKH}/2$

Undershoot: $V_{IL\ (AC)} \ge -0.5\ V$ for $t \le t_{KHKH}/2$

Power-up: $V_{IH} \leq V_{DDQ}$ + 0.3 V and $V_{DD} \leq$ 1.7 V and $V_{DDQ} \leq$ 1.4 V for $t \leq$ 200 ms

During normal operation, V_{DDQ} must not exceed V_{DD} . Control input signals may not have pulse widths less than t_{KHKL} (min) or operate at cycle rates less than t_{KHKH} (min).

- 4. To maintain a valid level, the transitioning edge of the input must:
 - a. Sustain a constant slew rate from the current AC level through the target AC level, $V_{IL\ (AC)}$ or $V_{IH\ (AC)}$.

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- b. Reach at least the target AC level.
- c. After the AC target level is reached, continue to maintain at least the target DC level, V_{IL (DC)} or V_{IH (DC)}.

AC Characteristics

 $(Ta = 0 \text{ to } +70^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V})$

			40		50	-	60		
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Unit	Notes
Average clock cycle time (K, /K, C, /C)	t _{KHKH}	4.00	8.40	5.00	8.40	6.00	8.40	ns	
Clock phase jitter (K, /K, C, /C)	t _{KC} var	_	0.20	_	0.20	_	0.20	ns	3
Clock high time (K, /K, C, /C)	t _{KHKL}	1.60	_	2.00	_	2.40	_	ns	
Clock low time (K, /K, C, /C)	t _{KLKH}	1.60	_	2.00	_	2.40	_	ns	
Clock to /clock (K to /K, C to /C)	t _{KH/KH}	1.80	_	2.20	_	2.70	_	ns	
/Clock to clock (/K to K, /C to C)	t/kHKH	1.80	_	2.20	_	2.70	_	ns	
Clock to data clock (K to C, /K to /C)	t _{KHCH}	0	1.10	0	1.60	0	2.10	ns	
DLL lock time (K, C)	t _{KC} lock	1,024	_	1,024	_	1,024	_	Cycle	2
K static to DLL reset	t _{KC} reset	30	_	30	_	30	_	ns	7
C, /C high to output valid	t _{CHQV}	_	0.45	_	0.45	_	0.50	ns	
C, /C high to output hold	t _{CHQX}	-0.45	_	-0.45	_	-0.50	_	ns	
C, /C high to echo clock valid	t _{CHCQV}	_	0.45	_	0.45	_	0.50	ns	
C, /C high to echo clock hold	t _{CHCQX}	-0.45	_	-0.45	_	-0.50	_	ns	
CQ, /CQ high to output valid	t _{CQHQV}	_	0.30	_	0.35	_	0.40	ns	4, 7
CQ, /CQ high to output hold	t_{CQHQX}	-0.30	_	-0.35	_	-0.40	_	ns	4, 7
C, /C high to output high-Z	t chqz		0.45		0.45		0.50	ns	5
C, /C high to output low-Z	t _{CHQX1}	-0.45		-0.45	_	-0.50		ns	5
Address valid to K, /K rising edge	t _{AVKH}	0.35		0.40	_	0.50	_	ns	1
Control inputs valid to K rising edge	t _{IVKH}	0.35	_	0.40	_	0.50	_	ns	1
Data-in valid to K, /K rising edge	t _{DVKH}	0.35	_	0.40	_	0.50	_	ns	1
K, /K rising edge to address hold	t _{KHAX}	0.35	_	0.40	_	0.50	_	ns	1
K, /K rising edge to control inputs hold	t _{KHIX}	0.35		0.40	—	0.50	_	ns	1
K, /K rising edge to data-in hold	t _{KHDX}	0.35		0.40	_	0.50		ns	1

Notes: 1. This is a synchronous device. All addresses, data and control lines must meet the specified setup and hold times for all latching clock edges.

- 2. V_{DD} slew rate must be less than 0.1 V DC per 50 ns for DLL lock retention. DLL lock time begins once V_{DD} and input clock are stable. It is recommended that the device is kept inactive during these cycles.
- 3. Clock phase jitter is the variance from clock rising edge to the next expected clock rising edge.
- 4. Echo clock is very tightly controlled to data valid / data hold. By design, there is a ±0.1 ns variation from echo clock to data. The datasheet parameters reflect tester guardbands and test setup variations.
- 5. Transitions are measured ±100 mV from steady-state voltage.
- 6. At any given voltage and temperature t_{CHQZ} is less than t_{CHQX1} and t_{CHQZ} less than t_{CHQY}.
- 7. These parameters are sampled.

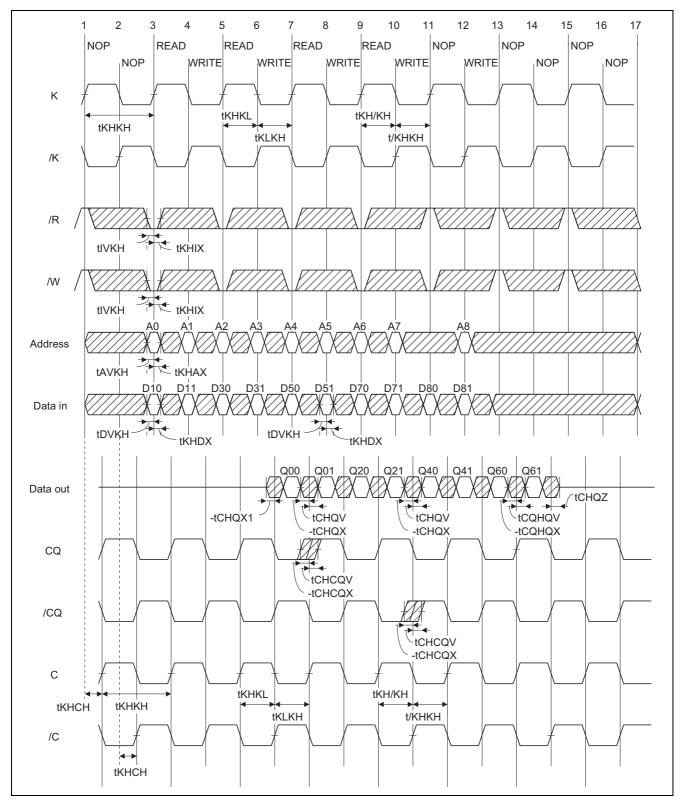
Remarks:

- 1. Test conditions as specified with the output loading as shown in AC Test Conditions unless otherwise noted.
- 2. Control input signals may not be operated with pulse widths less than t_{KHKL} (min).
- 3. If C, /C are tied high, K, /K become the references for C, /C timing parameters.
- 4. V_{DDQ} is +1.5 V DC.
- Control signals are /R, /W, /BW, /BW0, /BW1, /BW2 and /BW3. BWn signals must operate at the same timing as Data in.



Timing Waveforms

Read and Write Timing



Notes: 1. Q00 refers to output from address A0+0. Q01 refers to output from the next internal burst address following A0, i.e., A0+1.

- 2. Outputs are disable (high-Z) one clock cycle after a NOP.
- 3. In this example, if address A0 = A1, then data Q00 = D10, Q01 = D11. Write data is forwarded immediately as read results.
- 4. To control read and write operations, /BW signals must operate at the same timing as Data in.



JTAG Specification

These products support a limited set of JTAG functions as in IEEE standard 1149.1.

Disabling the Test Access Port

It is possible to use this device without utilizing the TAP. To disable the TAP controller without interfering with normal operation of the device, TCK must be tied to V_{SS} to preclude mid level inputs. TDI and TMS are designed so an undriven input will produce a response identical to the application of a logic 1,and may be left unconnected. But they may also be tied to V_{DD} through a $1k\Omega$ resistor.TDO should be left unconnected.

Test Access Port (TAP) Pins

Symbol I/O	Pin assignments	Description	Notes
TCK	2R	Test clock input. All inputs are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.	
TMS	10R	Test mode select. This is the command input for the TAP controller state machine.	
TDI	11R	Test data input. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is determined by the state of the TAP controller state machine and the instruction that is currently loaded in the TAP instruction.	
TDO	1R	Test data output. Output changes in response to the falling edge of TCK. This is the output side of the serial registers placed between TDI and TDO.	

Notes: The device does not have TRST (TAP reset). The Test-Logic Reset state is entered while TMS is held high for five rising edges of TCK. The TAP controller state is also reset on SRAM POWER-UP.

TAP DC Operating Characteristics

 $(Ta = 0 \text{ to } +70^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V})$

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Input high voltage	V _{IH}	+1.3	_	V _{DD} + 0.3	V	
Input low voltage	V _{IL}	-0.3	_	+0.5	V	
Input leakage current	ILI	-5.0	_	+5.0	μΑ	$0 \text{ V} \leq V_{IN} \leq V_{DD}$
Output leakage current	I _{LO}	-5.0	_	+5.0	μΑ	$\begin{array}{c} 0 \ V \leq V_{IN} \leq V_{DD}, \\ \text{output disabled} \end{array}$
Output low voltage	V _{OL1}	_	_	0.2	V	I _{OLC} = 100 μA
	V_{OL2}	_	_	0.4	V	I _{OLT} = 2 mA
Output high voltage	V _{OH1}	1.6			V	I _{OHC} = 100 μA
	V_{OH2}	1.4	_		V	I _{OHT} = 2 mA

Notes: 1. All voltages referenced to V_{SS} (GND).

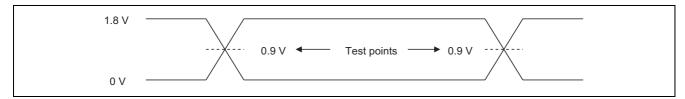
- 2. Power-up: $V_{IH} \le V_{DDQ} + 0.3 \text{ V}$ and $V_{DD} \le +1.7 \text{ V}$ and $V_{DDQ} \le +1.4 \text{ V}$ for $t \le 200 \text{ ms}$.
- 3. In "EXTEST" mode and "SAMPLE" mode, V_{DDQ} is nominally 1.5 V.
- 4. ZQ: $V_{IH} = V_{DDQ}$.



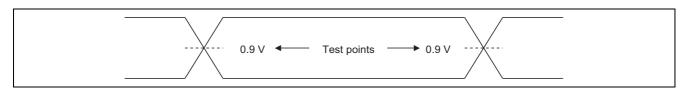
TAP AC Test Conditions

Parameter	Symbol	Conditions	Unit	Notes
Temperature	Та	0 ≤ Ta ≤ +70	°C	
Input timing measurement reference levels	V_{REF}	0.9	V	
Input pulse levels	V_{IL},V_{IH}	0 to 1.8	V	
Input rise/fall time	tr, tf	≤ 1.0	ns	
Output timing measurement reference levels		0.9	V	
Test load termination supply voltage (V _{TT})		0.9	V	
Output load		See figures		

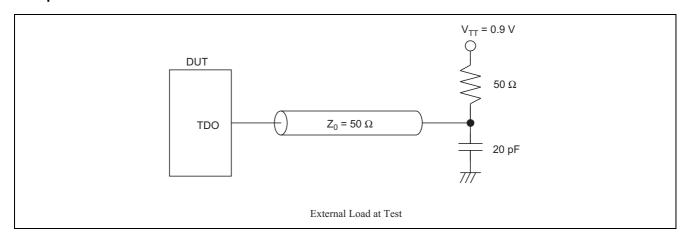
Input waveform



Output waveform



Output load condition



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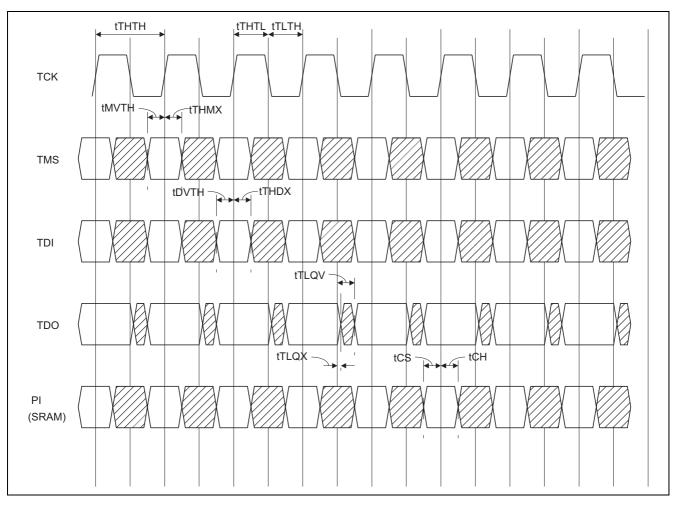
TAP AC Operating Characteristics

 $(Ta = 0 \text{ to } +70^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V})$

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Test clock (TCK) cycle time	t _{THTH}	100	_	_	ns	
TCK high pulse width	t _{THTL}	40	_	_	ns	
TCK low pulse width	t _{TLTH}	40	_	_	ns	
Test mode select (TMS) setup	t _{MVTH}	10	_	_	ns	
TMS hold	t _{THMX}	10	_	_	ns	
Capture setup	t _{CS}	10	_	_	ns	1
Capture hold	t _{CH}	10	_	_	ns	1
TDI valid to TCK high	t _{DVTH}	10	_	_	ns	
TCK high to TDI invalid	t _{THDX}	10	_	_	ns	
TCK low to TDO unknown	t _{TLQX}	0	_	_	ns	
TCK low to TDO valid	t _{TLQV}	_	_	20	ns	

Notes: 1. t_{CS} + t_{CH} defines the minimum pause in RAM I/O pad transitions to assure pad data capture.

TAP Controller Timing Diagram



Test Access Port Registers

Register name	Length	Symbol	Notes
Instruction register	3 bits	IR [2:0]	
Bypass register	1 bits	BP	
ID register	32 bits	ID [31:0]	
Boundary scan register	109 bits	BS [109:1]	

TAP Controller Instruction Set

IR2	IR1	IR0	Instruction	Description	Notes
0	0	1	EXTEST	The EXTEST instruction allows circuitry external to the component package to be tested. Boundary scan register cells at output balls are used to apply test vectors, while those at input balls capture test results. Typically, the first test vector to be applied using the EXTEST instruction will be shifted into the boundary scan register using the PRELOAD instruction. Thus, during the Update-IR state of EXTEST, the output driver is turned on and the PRELOAD data is driven onto the output balls. The IDCODE instruction causes the ID ROM to be loaded into the ID register when the controller is in capture-DR mode and places the ID	1, 2, 3
				register between the TDI and TDO balls in shift-DR mode. The IDCODE instruction is the default instruction loaded in at power up and any time the controller is placed in the Test-Logic-Reset state.	
0	1	0	SAMPLE-Z	If the SAMPLE-Z instruction is loaded in the instruction register, all RAM outputs are forced to an inactive drive state (high-Z), moving the TAP controller into the capture-DR state loads the data in the RAMs input into the boundary scan register, and the boundary scan register is connected between TDI and TDO when the TAP controller is moved to the shift-DR state.	3, 4
0	1	1	RESERVED	The RESERVED instructions are not implemented but are reserved for future use. Do not use these instructions.	
1	0	0	SAMPLE (/PRELOAD)	When the SAMPLE instruction is loaded in the instruction register, moving the TAP controller into the capture-DR state loads the data in the RAMs input and I/O buffers into the boundary scan register. Because the RAM clock(s) are independent from the TAP clock (TCK) it is possible for the TAP to attempt to capture the I/O ring contents while the input buffers are in transition (i.e., in a metastable state). Although allowing the TAP to SAMPLE metastable input will not harm the device, repeatable results cannot be expected. Moving the controller to shift-DR state then places the boundary scan register between the TDI and TDO balls.	3
1	0	1	RESERVED		
1	1	0	RESERVED		
1	1	1	BYPASS	The BYPASS instruction is loaded in the instruction register when the bypass register is placed between TDI and TDO. This occurs when the TAP controller is moved to the shift-DR state. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.	

Notes: 1. Data in output register is not guaranteed if EXTEST instruction is loaded.

- 2. After performing EXTEST, power-up conditions are required in order to return part to normal operation.
- 3. RAM input signals must be stabilized for long enough to meet the TAPs input data capture setup plus hold time (t_{CS} plus t_{CH}). The RAMs clock inputs need not be paused for any other TAP operation except capturing the I/O ring contents into the boundary scan register.
- 4. Clock recovery initialization cycles are required to return from the SAMPLE-Z instruction.



Boundary Scan Order

Ball ID			Signal names		s
1 6R /C /C /C 2 6P C C C 3 6N SA SA SA 4 7P SA SA SA 5 7N SA SA SA 6 7R SA SA SA 8 8P SA SA SA 8 8P SA SA SA 9 9R SA SA SA 9 9	Bit #	Ball ID			
2 6P C C C 3 6N SA SA SA 4 7P SA SA SA 5 7N SA SA SA 6 7R SA SA SA 8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0					
3 6N SA SA SA 4 7P SA SA SA 5 7N SA SA SA 6 7R SA SA SA 7 8R SA SA SA 8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC Q1 Q1 15 11N NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 <					
4 7P SA SA SA 5 7N SA SA SA 6 7R SA SA SA 7 8R SA SA SA 8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 11 10P D0 D0 D0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC NC Q9 14 10M NC NC D10 17 9N NC NC D10 17 9N NC NC D10 17 9N NC NC NC					
5 7N SA SA SA 6 7R SA SA SA 7 8R SA SA SA 8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 11 10P D0 D0 D0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC NC Q9 14 10M NC NC Q9 14 10M NC NC Q1 15 11N NC NC Q10 17 9N NC NC Q10 18 11L Q1 Q2 Q2					
6 7R SA SA SA 7 8R SA SA SA 8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 11 10P D0 D0 D0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC NC D1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 20 9L NC NC D11 21 10L NC NC D11					
7 8R SA SA SA 8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC D9 14 10M NC NC Q9 14 10M NC NC Q9 14 10M NC NC D10 15 11N NC NC D10 16 9M NC NC D10 17 9N NC NC D10 17 9N NC NC D10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2					
8 8P SA SA SA 9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC Q1 Q1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC D10 17 9N NC NC D10 17 9N NC NC D10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC D11 21 10L NC NC D11 22 11K NC NC NC D12 <td></td> <td></td> <td></td> <td></td> <td></td>					
9 9R SA SA SA 10 11P Q0 Q0 Q0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC Q1 Q1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC Q11 21 10L NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC Q12 <					
10 11P Q0 Q0 Q0 11 10P D0 D0 D0 12 10N NC NC D9 13 9P NC NC Q9 14 10M NC Q1 Q1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC Q11 21 10L NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC D12					
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12 10N NC NC D9 13 9P NC NC Q9 14 10M NC Q1 Q1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC Q10 18 11L Q1 Q2 Q2 20 9L NC NC D10 20 9L NC NC D11 21 10L NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC NC D12 25 9K NC NC Q12					
13 9P NC NC Q9 14 10M NC Q1 Q1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC D11 21 10L NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4					
14 10M NC Q1 Q1 15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC NC D11 21 10L NC NC D11 D2 D2 20 9L NC NC NC Q11 Q2 Q2 Q2 Q3 Q					
15 11N NC D1 D1 16 9M NC NC D10 17 9N NC NC D10 17 9N NC NC D10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC NC D11 21 10L NC NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC NC D12 25 9K NC NC NC D12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 1					
16 9M NC NC D10 17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC NC D12 25 9K NC NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 11H ZQ ZQ ZQ 29 10G NC NC D13 30 9G NC NC NC D13 31 1					
17 9N NC NC Q10 18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC NC D12 25 9K NC NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 11H ZQ ZQ ZQ 29 10G NC NC D13 30 9G NC NC Q5 Q5 32 11					
18 11L Q1 Q2 Q2 19 11M D1 D2 D2 20 9L NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 11H ZQ ZQ ZQ 29 10G NC NC D13 30 9G NC NC Q13 31 11F NC Q5 Q5 32 11G NC D5 D5 33 9F NC NC D14 34 10F NC NC Q14					
19 11M D1 D2 D2 20 9L NC NC D11 21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 11H ZQ ZQ ZQ 29 10G NC NC D13 30 9G NC NC Q13 31 11F NC Q5 Q5 32 11G NC D5 D5 33 9F NC NC NC D14 34 10F NC NC Q14 35 11E Q3 <td< td=""><td></td><td></td><td></td><td></td><td></td></td<>					
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21 10L NC NC Q11 22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 11H ZQ ZQ ZQ 29 10G NC NC D13 30 9G NC NC Q13 31 11F NC Q5 Q5 32 11G NC D5 D5 33 9F NC NC D14 34 10F NC NC Q14 35 11E Q3 Q6 Q6 36 10E D3 D6 D6 37 10D NC NC NC <td< td=""><td></td><td></td><td></td><td></td><td></td></td<>					
22 11K NC Q3 Q3 23 10K NC D3 D3 24 9J NC NC D12 25 9K NC NC Q12 26 10J Q2 Q4 Q4 27 11J D2 D4 D4 28 11H ZQ ZQ ZQ 29 10G NC NC D13 30 9G NC NC Q13 31 11F NC Q5 Q5 32 11G NC D5 D5 33 9F NC NC D14 34 10F NC NC Q14 35 11E Q3 Q6 Q6 36 10E D3 D6 D6 37 10D NC NC NC Q15 39 10C NC Q7 <td< td=""><td></td><td></td><td></td><td></td><td></td></td<>					
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45 9B NC NC D17 46 10B NC NC Q17 47 11A CQ CQ CQ 48 10A SA NC NC	43	11B	Q4	Q8	Q8
46 10B NC NC Q17 47 11A CQ CQ CQ 48 10A SA NC NC	44	11C	D4	D8	D8
47 11A CQ CQ CQ 48 10A SA NC NC	45	9B	NC	NC	D17
48 10A SA NC NC	46	10B	NC	NC	Q17
	47	11A	CQ	CQ	CQ
49 9A SA SA SA	48	10A	SA	NC	NC
	49	9A	SA	SA	SA

		Signal names		
Bit #	Ball ID	х9	x18	x36
50	8B	SA	SA	SA
51	7C	SA	SA	SA
52	6C	SA	SA	SA
53	8A	/R	/R	/R
54	7A	NC	NC	/BW1
55	7B	/BW	/BW0	/BW0
56	6B	K	K	K
57	6A	/K	/K	/K
58	5B	NC	NC	/BW3
59	5A	NC	/BW1	/BW2
60	4A	/W	/W	/W
61	5C	SA	SA	SA
62	4B	SA	SA	SA
63	3A	SA	SA	NC
64	2A	V _{SS}	V _{SS}	V _{SS}
65	1A	/CQ	/CQ	/CQ
66	2B	NC	Q9	Q18
67	3B	NC	D9	D18
68	1C	NC	NC	D27
69	1B	NC	NC	Q27
70	3D	NC	Q10	Q19
71	3C	NC	D10	D19
72	1D	NC	NC	D28
73	2C	NC	NC	Q28
74	3E	Q5	Q11	Q20
75	2D	D5	D11	D20
76	2E	NC	NC	D29
77	1E	NC	NC	Q29
78	2F	NC	Q12	Q21
79	3F	NC	D12	D21
80	1G	NC	NC	D30
81	1F	NC	NC	Q30
82	3G	Q6	Q13	Q22
83	2G	D6	D13	D22
84	1H	/DOFF	/DOFF	/DOFF
85	1J	NC	NC	D31
86	2J	NC	NC	Q31
87	3K	NC	Q14	Q23
88	3J	NC	D14	D23
89	2K	NC	NC	D32
90	1K	NC	NC	Q32
91	2L	Q7	Q15	Q24
92	3L	D7	D15	D24
93	1M	NC	NC	D33
94	1L	NC	NC	Q33
95	3N	NC	Q16	Q25
96	3M	NC	D16	D25
97	1N	NC	NC	D34
98	2M	NC	NC	Q34



		Signal names		
Bit #	Ball ID	х9	x18	x36
99	3P	Q8	Q17	Q26
100	2N	D8	D17	D26
101	2P	NC	NC	D35
102	1P	NC	NC	Q35
103	3R	SA	SA	SA
104	4R	SA	SA	SA

		Signal names		
Bit #	Ball ID	х9	x18	x36
105	4P	SA	SA	SA
106	5P	SA	SA	SA
107	5N	SA	SA	SA
108	5R	SA	SA	SA
109	_	INTERNAL	INTERNAL	INTERNAL

Notes: In boundary scan mode,

- 1. Clock balls (K, /K, C, /C) are referenced to each other and must be at opposite logic levels for reliable operation.
- 2. CQ and /CQ data are synchronized to the respective C and /C (except EXTEST, SAMPLE-Z).
- 3. If C and /C tied high, CQ is generated with respect to K and /CQ is generated with respect to /K (except EXTEST, SAMPLE-Z).
- 4. ZQ must be driven to V_{DDQ} supply to ensure consistent results.

ID Register

Part	Revision number (31:29)	Type number (28:12)	Vendor JEDEC code (11:1)	Start bit (0)
_	_	0 0MMM 0WW0 10Q0 B0S0	_	_
R1Q2A3636B	000	0 0010 0110 1010 0010	0100 0100 011	1
R1Q2A3618B	000	0 0010 0100 1010 0010	0100 0100 011	1
R1Q2A3609B	000	0 0010 0000 1010 0010	0100 0100 011	1

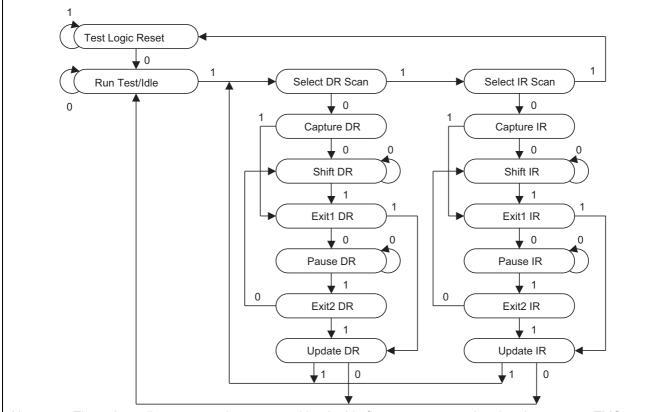
Notes: 1. Type number

MMM :Density 011:72Mb, 010:36Mb, 001:18Mb

WW :Organization 11: x 36, 10: x 18, 00: x 9, 01: x 8

Q :QDR/DDR 1: QDR, 0: DDR
B :Burst lengths 1: 4-word burst, 0: 2-word burst
S :I/O 1: Separate I/O, 0: Common I/O

TAP Controller State Diagram

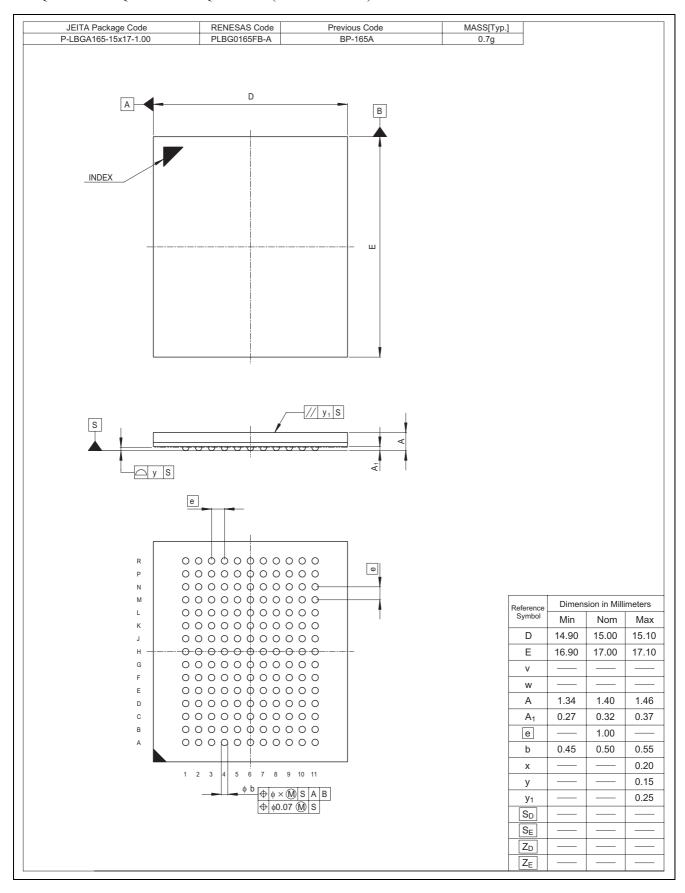


Notes: The value adjacent to each state transition in this figure represents the signal present at TMS at the time of a rising edge at TCK.

No matter what the original state of the controller, it will enter Test-Logic-Reset when TMS is held high for at least five rising edges of TCK.

Package Dimensions

R1Q2A3636B/R1Q2A3618B/R1Q2A3609B (PLBG0165FB-A)



Revision History

R1Q2A3636B/R1Q2A3618B/R1Q2A3609B Data Sheet

Rev.	Date		Contents of Modification
		Page	Description
0.01	Jan.31, 2008	_	Initial issue
0.02	Feb.29,2008	P7 P14	DLL Constraints 2.the lower end of the frequency at which the DLL can operate is 119MHz AC characteristics Average clock cycle time is enlarged t _{KHKH} (-40)(max) 8.40ns, t _{KHKH} (-50)(max) 8.40ns, t _{KHKH} (-60)(max) 8.40ns
0.03	Apr.11,2008	P2	Ordering Infomatuon: Adding Part Number and Marking Name 1.Part Number (9) R: 1stGeneration,A: 2ndGeneration,B: 3rdGeneration (10:11) BG: Package type=BGA (12:13) 60: Cycle time=6.0 ns,50: Cycle time=5.0 ns,40: Cycle time=4.0 ns 33: Cycle time=3.3 ns (14) R: Temperature range= 0°C~ 70°C,I: Temperature range= -40°C~ 85°C (15) B: Pb-free,T: Tape&Reel,S: Pb-free and Tape&Reel None: Standard (Pb and Tray) (16) 0 to 9, A to Z: Renesas internal use 2.Marking Name Marking Name(0:14) =Part Number (0:14)

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- Renesas lechnology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Notes:

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